

# **EDISON Project in Nanophysics/electronics**

## **- Current status of contents and service -**

**Hoon Ryu, Ph.D.**

**National Institute of Supercomputing and Networking,  
Korea Institute of Science and Technology Information.**

**elec1020@gmail.com**

# Technology-Computer-Aided-Design



## TCAD?

- Group of tools
  - Predict “real world” by computing, critical to save time/money/manpower etc.
- Large-scale problems in various fields of science
  - With aids of HPC. “Computational Science” now “an area of research”

**If you are a developer and a scientist - OK. I know you’re great, BUT**

- Should a person know everything to do modeling/simulation-based research?

```
1 //*
2 /**
3 // Copyright ( C ) Microsoft, 1994 - 2002.
4 /**
5 // File:      regexpr2.cpp
6 /**
7 // Contents: implementation for rpattern methods, definitions for all the
8 //             subexpression types used to perform the matching, the
9 //             charset class definition .
10 /**
11 #include <stdio.h>
12 #include <float.h>
13 /**
14 int main()
15 {
16     // Open the data file
17     FILE* pFile = fopen( "data.dat", "rb" );
18     if( pFile == NULL )
19     {
20         assert( false );
21         return 1;
22     }
23
24     /* Read data from File */
25     if( fread(szBuf, 100, 1, pFile) != 1 )
26     {
27         fclose( pFile );
28         return 1;
29     }
30
31     /* Close File */
32     fclose( pFile );
33     return 0;
34 }
```

# Technology-Computer-Aided-Design



## TCAD?

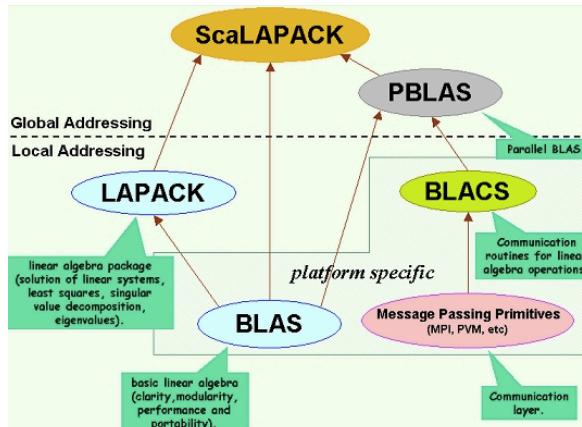
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## Parallel Programming in C with MPI and OpenMP



## TCAD?

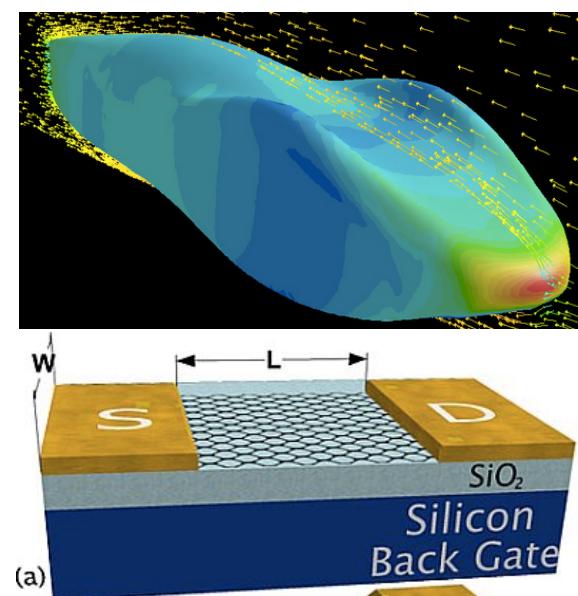
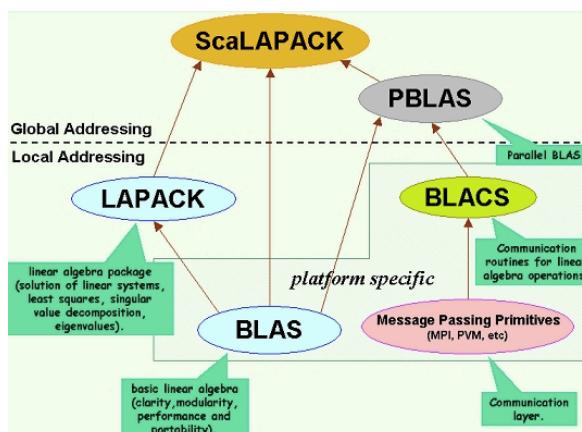
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## Why don’t we make people a bit happier?

- Easy Access to Simulations
- Efficiency of Learning – Let people experience interactively!
- Strong motivation to “Take the pain” for learning all the technical details

# Science Gateway: The EDISON Project



“Easy Simulation” is the keyword for increasing efficiency in EDU/Research!!

## Initiation of the EDISON Project

(EDucation-research Integration through Simulation On the Net)

- Started in 2011 July under governmental support
- Initiative domain: Computational Fluids Dynamics (CFD)

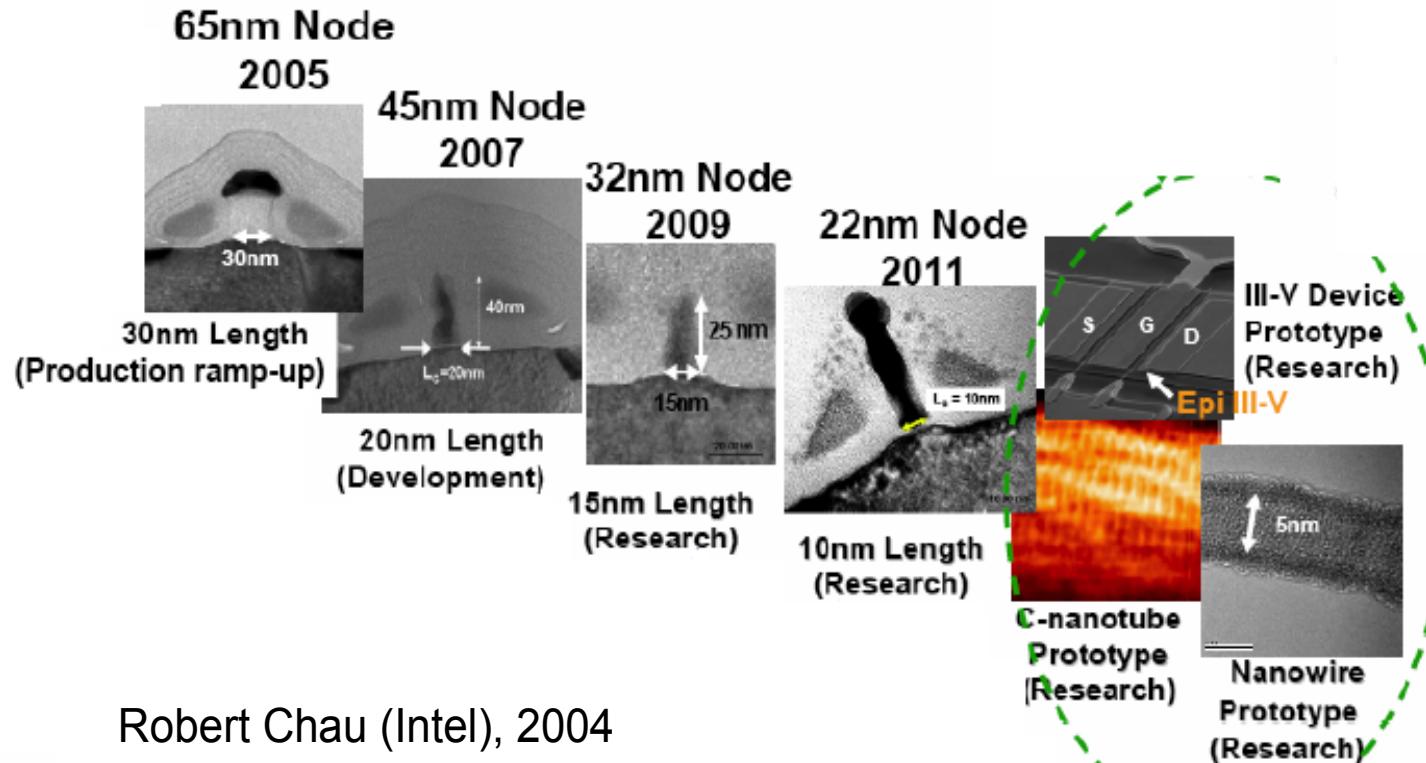
## Moving to the 2<sup>nd</sup> step: Towards “new” scientific domains.

- 2012 July, we have started to support two new domains
  - Computational Chemistry and Computational Nanophysics

## Objective of remaining talk – Focusing on the nanophysics

- A brief Introduction of EDISON\_Nanophysics
  - Motivation and Objectives
  - Current Status of Services
  - Summary of available TCAD software

# Nano + Physics + Electronics?



**Small – everything is new in terms of theory**

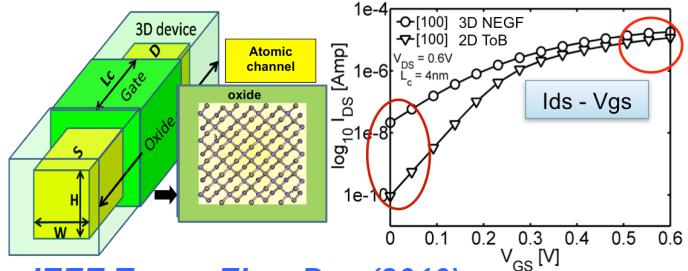
- Nanoscale Materials
- Nanoscale Devices
- **Fundamentals of Theory**
  - \* Solid-state, Quantum Physics, Semiconductors Crystalline ETC

# Nano+Physics+Electronics - Research



## Si Devices: Transport in FETs

- Performance-degradation in nanoscale FETs.
- Needs for 3-D NEGF simulation.



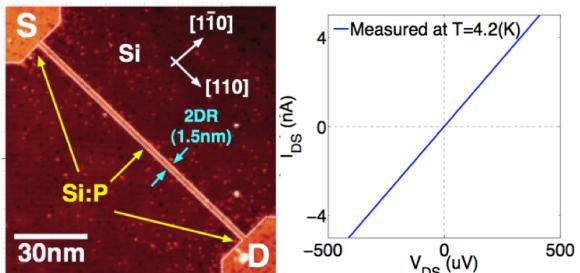
IEEE Trans. Elec. Dev (2010)

IEEE Trans. Nanotech. (2012)

IEEE Elec. Dev. Lett. (Under Review)

## New Material: Si:P Devices

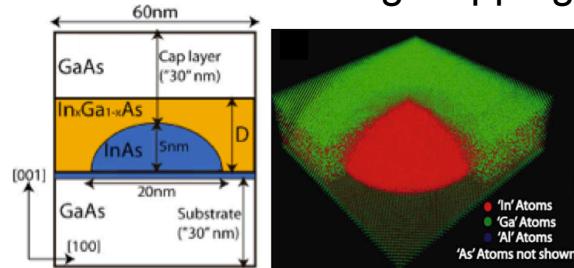
- Metallic Property of P δ-doped Nanowires.
- Sensitivity to channel dopant distributions.



Phys. Rev. B (2011), Science (2012),  
Nat. Nanotech. (2012, 2014) Nanoscale (2013)

## III-V Devices: Optoelectronics - Photodetectors

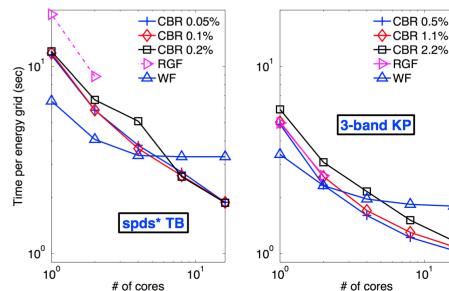
- Engineering of III-V Quantum Dot Optical Gaps with Strain-reducing Capping Layers.



IEEE Trans. Nanotech. (2009)  
Math. Comp. Model. (2013)

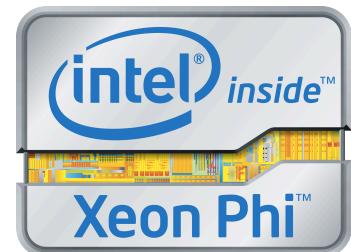
## Algorithm: Parallel Solver

- Quantum Transport: Contact Block Reduction vs. Recursive Green's Function.



J. Appl. Phys. (2012)

Math. Comp. Model. (Under Review)



# Nano+Physics+Electronics - Education



## Physics Fundamentals

## Advanced Materials

## Advanced Devices

Electronic/Electrical Engineering

Semiconductor Fundamentals

Device Electronics

CMOS and Non-CMOS Devices

Materials Science and Engineering

Semiconductor Crystalline

Structure Relaxations

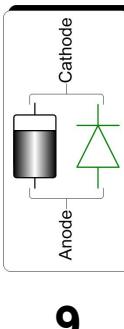
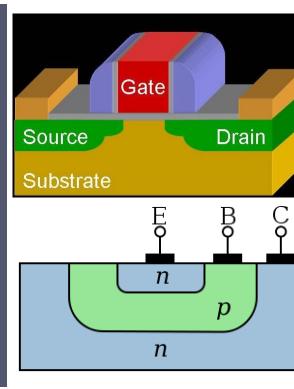
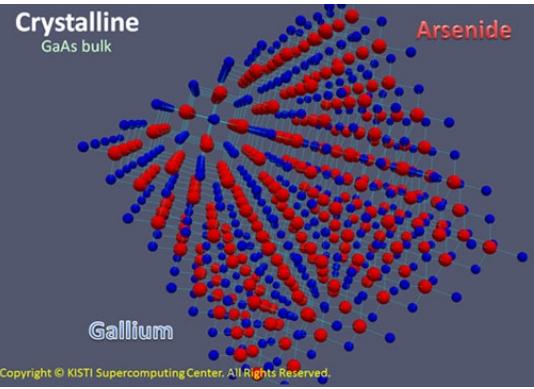
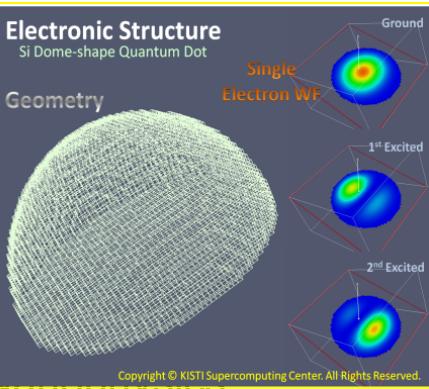
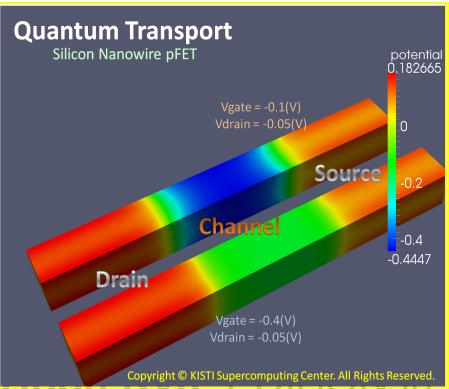
Nanocrystals, Advanced Materials

Physics

General Physics Fundamentals

Solid-state Physics

Semiclassical and Quantum Physics



# EDISON\_Nanophysics: Available TCAD SWs

- As of today, a total of 45 TCAD Tools are available
- Tools are categorized by a set of problem filters
  - Five big categories: Geometry/Material/Device/Problem/Structure Representation

Geometry	Material	Device Type	Problem Type	Structure Rep.
1D	Si	Bulk Devices	Drift-Diffusion	Ab-initio
2D	Si/Ge	Nanowires	Quantum Transport	Effective Mass
3D	III-V	Quantum-wells	Electronic Structure	<i>k.p</i>
	C	Quantum-dots	Boltzmann Transport	Tight-binding
	Others	Others	Optical Properties	Semi-classical
			Crystal Structures	Others
			Physics Education	
			Others	
(a) Geometry Description	Number of Tools	(c) Device Type	Number of Tools	(e) Structure Representation
1D	24	Bulk Devices	10	Ab-initio
2D	9	Nanowire	9	Effective Mass
3D	12	Quantum-well	5	<i>k.p</i>
		Quantum-dot	1	Tight-binding
		Others	25	Semi-classical
				Others
(b) Device Material	Number of Tools	(d) Problem Type	Number of Tools	Number of Tools
Si	14	Drift-Diffusion	4	Ab-initio
SiGe	0	Quantum Transport	4	Effective Mass
III-V	10	Electronic Structure	10	<i>k.p</i>
Carbon	4	Optical Properties	1	Tight-binding
Others	34	Crystal Structure	4	Semi-classical
		Physics Education	5	Others
		Others	21	

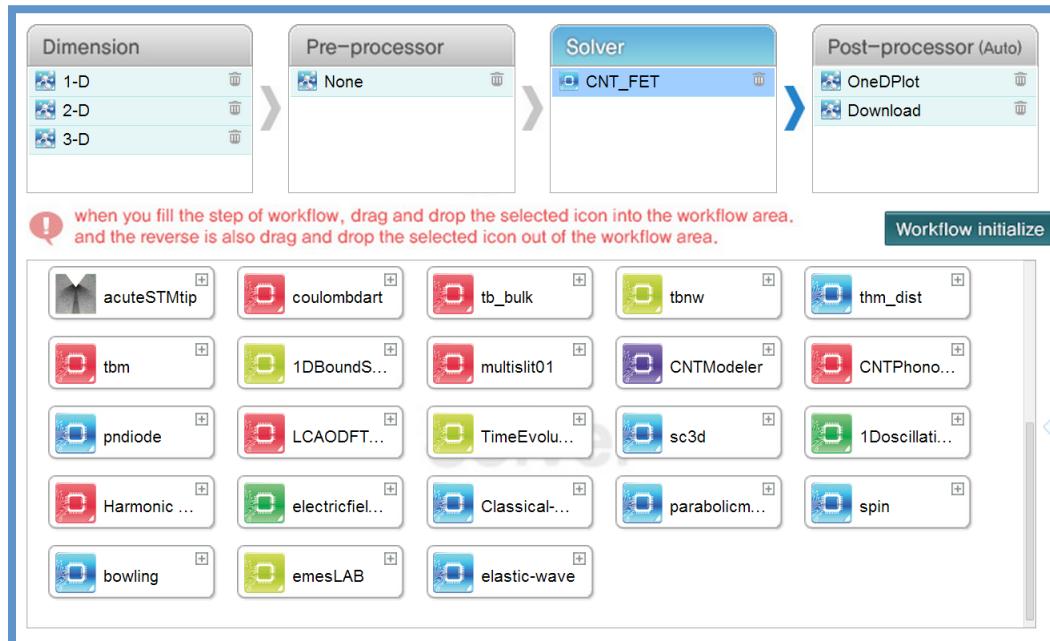
# EDISON Nanophysics: Web-based Service



## • Remarks

- **Native-web interface:** Do not invoke GUIs through X-term. Light - a clear strength in resource overhead for supporting multiple job requests.
- **Job monitoring:** Submitted jobs runs in the backend HPC. Provides a control interface of submitted jobs – In the case of X-term GUIs?
- **Easy Postprocessing:** Simple, intuitive ways of visualizations and data-downloading

## • Four steps to support “easy simulations”



Users can select preferred tools either by:

- combine workflow components
- combine problem filtering condns.  
(Will show later again)

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- **Four steps to support “easy simulations”**

Parameter info		
Name	Sweep	Value
Temperature		300.0000 <input type="button" value="?"/>
CNT Chirality index m		13 <input type="button" value="?"/>
Source Doping Type	<input type="button" value="n(n-type)"/> <input type="button" value="?"/>	<ul style="list-style-type: none"><li>n(n-type)</li><li><b>n(n-type)</b></li><li>i(intrinsic)</li><li>p(p-type)</li><li>s(Schottky)</li></ul>
Channel Doping Type		<input type="button" value="?"/>
Drain Doping Type	<input type="button" value="n(n-type)"/> <input type="button" value="?"/>	
Source Doping Density		1.00e+07 <input type="button" value="?"/>

Control simulation parameters

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Control simulation parameters

Index	UserID	Solver name Job name	Detail info	Submit time	Complete time (Wait time/Run time)	State
21	edison	CNT_FET CNT_FET	<input type="button" value=""/>	2014-04-01 00:19:13	(00:00:00 / Running)	<span>running</span>
20	edison	CNT_FET CNT_FET	<input type="button" value=""/>	2014-04-01 00:15:31	(00:00:00 / Running)	<span>running</span>
19	cp4419	CNT_FET	<input type="button" value=""/>	2014-03-07 14:44:36	2014-03-07 14:44:36 (00:00:01 / 00:40:50)	<span>success</span>
18	cp4419	CNT_FET a	<input type="button" value=""/>	2014-03-06 13:36:25	(00:00:02 /)	<span>cancel</span>

Check the status of submitted simulation jobs

Hoon Ryu, EDISON in Nanophysics

13

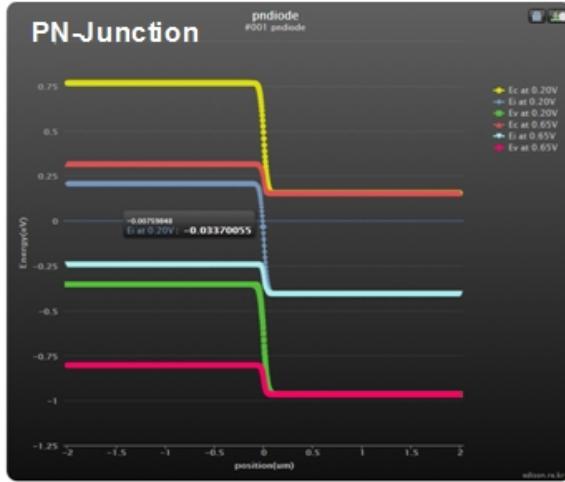
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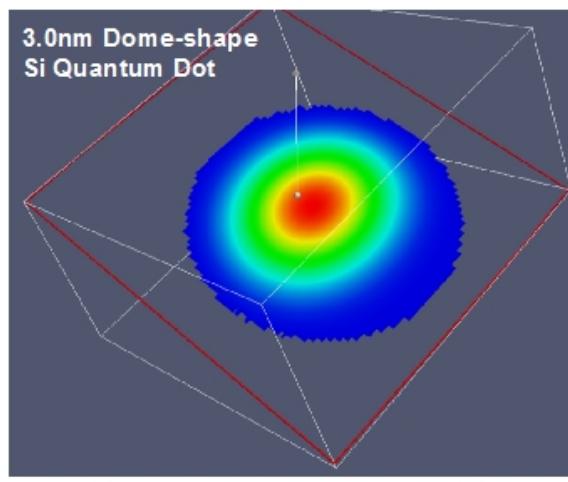
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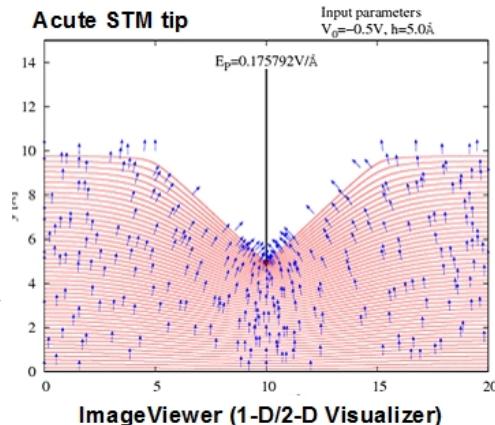
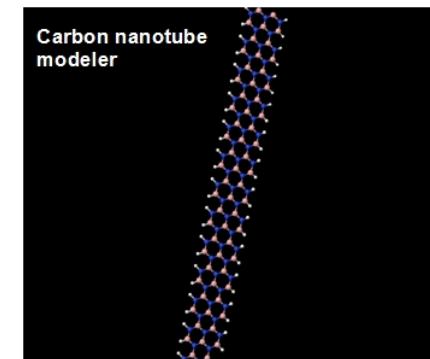
## • Four steps to support “easy simulations”



OneDplot (1-D Visualizer)



Paraview (2-D/3-D Visualizer)



ImageViewer (1-D/2-D Visualizer)

- 4 Vis. Interf.: oneDplot, Paraview (VTK), Jmol, Imageviewer
- Directly downloadable for local processing

# Current Status of Service Utilizations

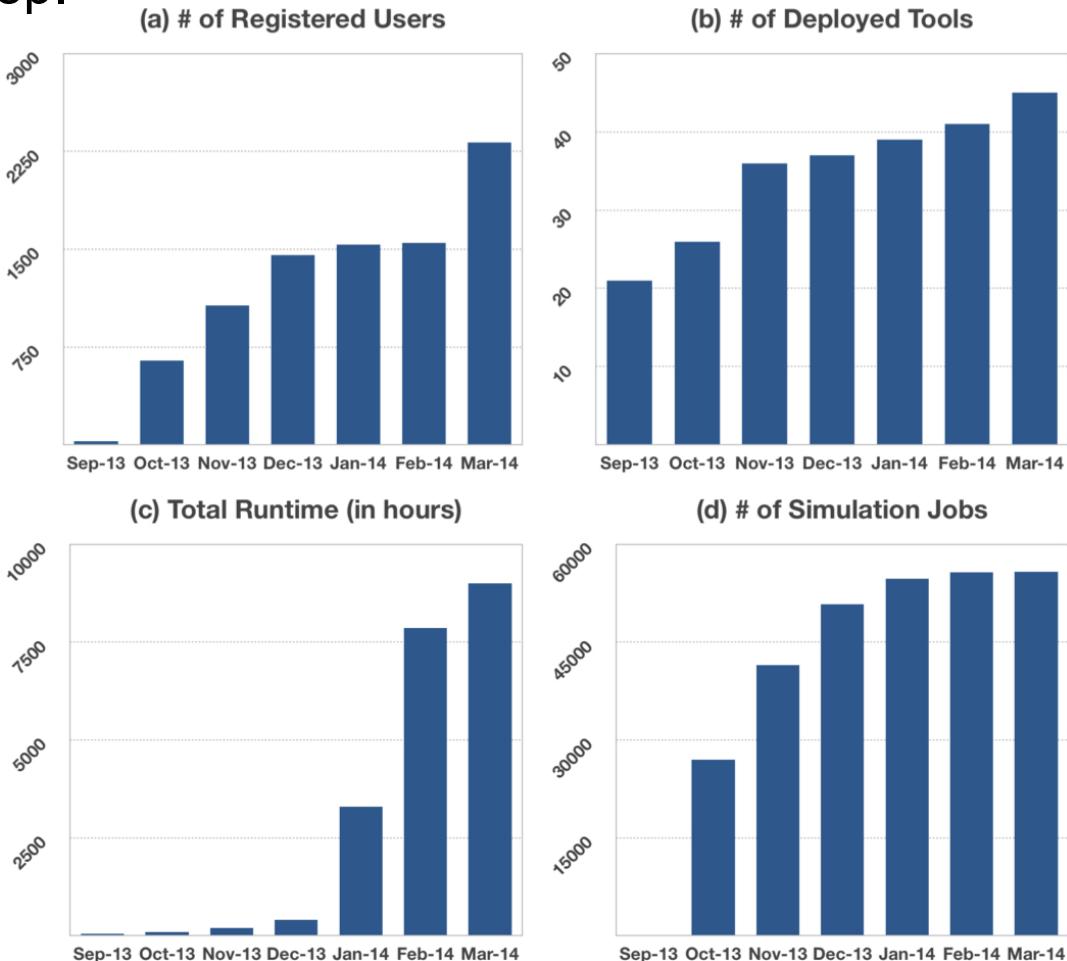


## • Service Statistics

- Full service opened in 2013-Sep.
- 2300 domestic users.
- 45 TCAD Tools
- 50K jobs with wall-time of ~8K hours

## • Remarks

- 60 classes in 30 domestic universities.
- “Open universities” have joined our customers
  - \*\* Korea National Open Univ.
    - Biggest and Oldest National Universities.
- We want to hear from you now!



# EDISON\_Nanophysics GLOBAL



## • EDISON\_Nanophysics for global users (~ 2014.Mar)

- 8 most popular tools are currently available. (Tool migration is ongoing)
- <http://nano.edison-project.org> - Migration will be completed soon.

The screenshot shows the EDISON\_Nanophysics web interface. At the top, there are tabs for 'ABOUT', 'SCIENCE APPSTORE', and 'SIMULATION'. The 'SIMULATION' tab is active, displaying a simulation visualization of a 'Crystalline GaAs bulk' with 'Arsenic' atoms and electron density plots for 'Ground', '1st Excited', and '2nd Excited' states. Below this, there's a 'Login' section and a world map showing simulation locations. The main content area includes 'System Resource Statistics' (Cluster: 16, Total: 0, Used: 0, Avail: 16) and sections for 'Notice' and 'FAQ'. A 'Popular Solver' section lists several simulation tools with their versions and authors, such as 'Particle-in-a-Well problem simulation LAB' by KISTI and 'P-N JUNCTION diode simulation LAB based on Drift-Diffusion...' by Hoon Ryu. At the bottom, a 'Problem Filter' table lists various simulation tools with columns for Index, SW name, Version, Affiliation, Name, Date, Manual, and Run buttons.

Index	SW name	Version	Affiliation	Name	Date	Manual	Run
8	1D Harmonic oscillator problem simulation LAB	Ver 1.0	KISTI	Inho Jeon	2014-03-10	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
7	Particle-in-a-Well problem simulation LAB	Ver 1.0	KISTI	Hoon Ryu	2013-08-29	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
6	P-N JUNCTION diode simulation LAB based on Drift-Diffusion equation	Ver 1.0	KISTI	Hoon Ryu	2013-08-29	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
5	Nano-MOS device simulation SW	Ver 1.0	KAIST	Ki-Hoon Park	2013-08-29	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
4	Carbon NanoTube (CNT) FET simulation SW	Ver 1.0	KAIST	Mincheol Shin	2013-08-29	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
3	Nanowire FET simulation SW	Ver 1.0	KAIST	Mincheol Shin	2013-08-29	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
2	Electric field and potential-energy simulation LAB	Ver 1.0	KISTI	Hoon Ryu	2014-03-10	<input type="button" value="Manual"/>	<input type="button" value="Run"/>
1	Parabolic motion problem simulation LAB	Ver 1.0	KISTI	Hoon Ryu	2014-03-11	<input type="button" value="Manual"/>	<input type="button" value="Run"/>

## Tool Description

1D Harmonic Oscillator Problem Simulation LAB

Particle-in-a-box Problem Simulation LAB

P/N Junction Diode Simulation LAB

Nano-MOS Device Simulation LAB

Carbon NanoTube FET Simulation LAB

Nanowire FET Simulation LAB

Electric-field and Potential-energy Simulation LAB

Parabolic-motion Problem Simulation LAB

Physics  
Fundamentals

Semiconductor  
Fundamentals

Advanced  
Nanoscale Devices

- User-guides to support self-study
- Further Details: Demo Tomorrow!

# Conclusions



- **A brief Introduction of EDISON\_Nanophysics is given**
  - Motivation and Objectives
  - Current Status of Services
  - Summary of available TCAD software
- **Please consider EDISON for teaching and learning nanoscience in your school/institutes**
  - <http://nano.edison-project.org>
  - Will give you further details about service tomorrow
- **Inquiries/Questions**
  - Dr. Ruth Lee ([jsruthlee@kisti.re.kr](mailto:jsruthlee@kisti.re.kr)) or Me ([elec1020@gmail.com](mailto:elec1020@gmail.com))
  - Any fruitful comments would be appreciated
- **Do we have more time?**
  - Yes! then next.
  - Thank you otherwise. ☺

# P/N Junction Diode Simulation LAB



## Objective:

- Diode: 2-terminal devices
- Electronic performance of P/N junction diode – Design guide-line.

## Platform of Development:

- C++, ARPACK - Serial runs only

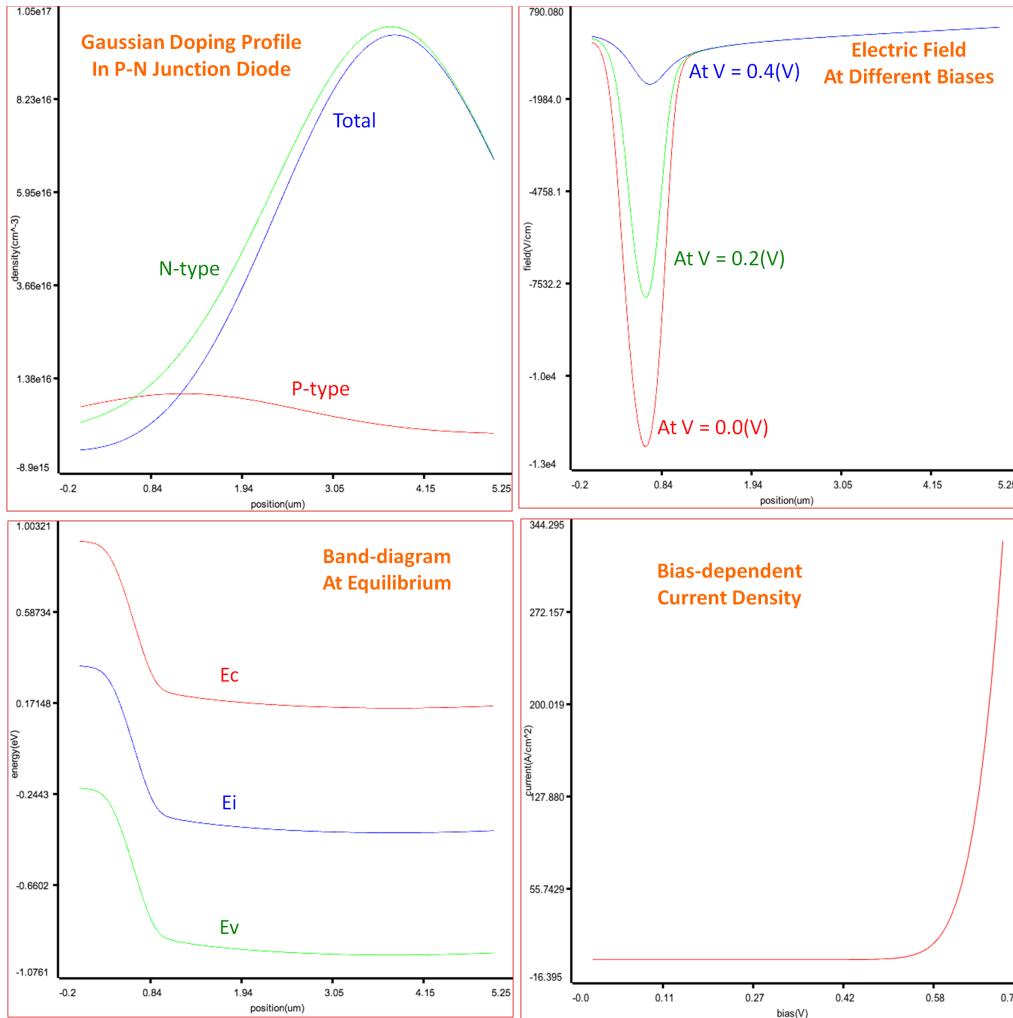
## Features:

- Calculate I-V characteristic of 2-terminal diode devices
- Drift-diffusion equation
- Support various doping profiles with which the I-V characteristic is hard to be computed with hands

## Target of classes:

- Fundamentals of semiconductors
- Electronic Circuits

## P/N Junction Diode: Gaussian doping profile



# Carbon NanoTube Simulation LAB



## Objective:

- Simulate the electronic performance of CNT using a full quantum mechanical approach

## Platform of Development:

- C++, PETSc – Support parallel runs

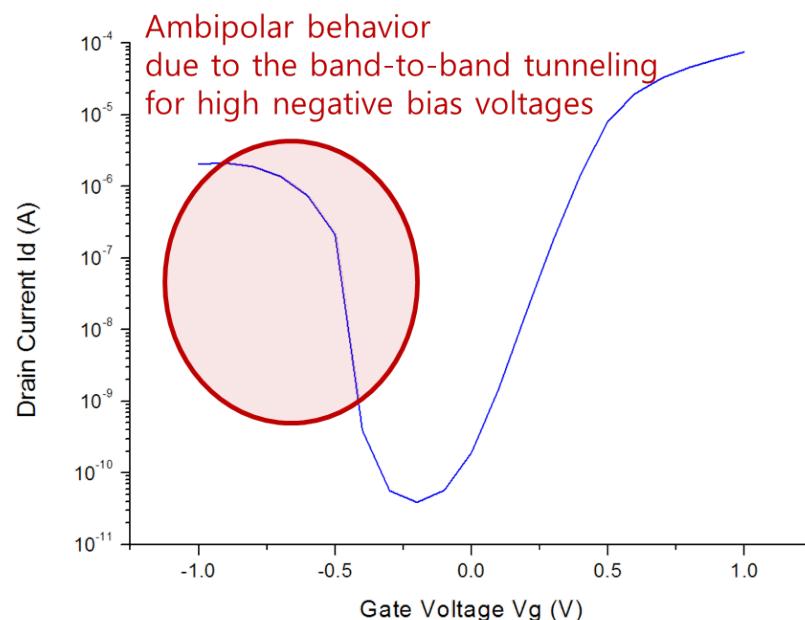
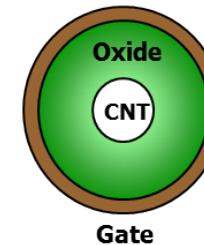
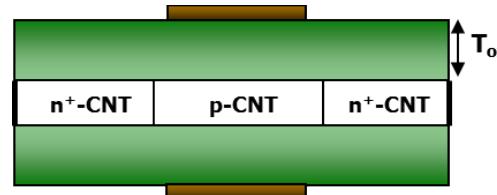
## Features:

- I-V calculations using Non-Equilibrium Green's Function (NEGF)
- Ballistic Transport

## Target of classes:

- Advanced nanoscale devices
- Research purpose

R=1nm, (13, 0) zig-zag pattern CNT



# Electric-field and Potential-energy Sim. LAB



## Objective:

- Simulate the field and potential profiles for arbitrarily placed point charges

## Platform of Development:

- C++ and FDM/Aztec Linear Solver

## Features:

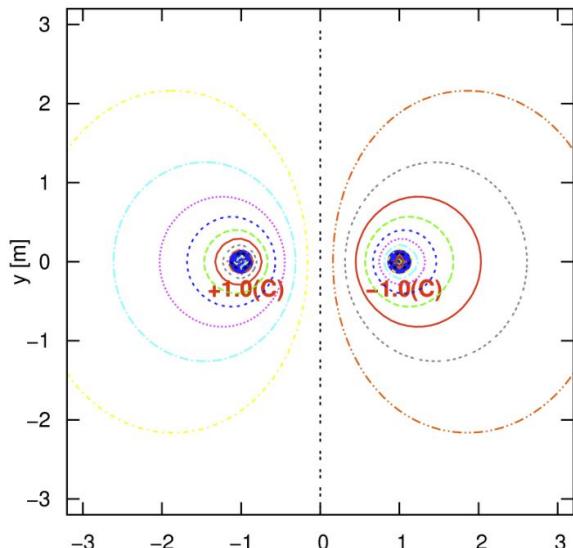
- Solve 2D Poisson Equations

## Target of classes:

- Fundamentals of Physics
- Fundamentals of Electromagnetic

## Two point charges: +1/-1 (C)

Equi-potential  
Contours



Electric  
Fields

